NSN 5962-01-263-9395

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-263-9395 **Body Length:** 0.440 inches **Body Width:** 0.290 inches **Body Height:** 0.120 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and w/strobe and w/buffered output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Case Outline Source And Designator:** C-10 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -1.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 150.00 nanoseconds propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 leadless Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

NSN 5962-01-263-9395

Memory Microcircuit - Page 2 of 2



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